

# Curriculum Vitae



**Dr. Ganesh Shridhar Hegde**

**Ph.D., M.Sc.**

**Assistant Professor**

**PG Coordinator**

Dept of Physics

Post Graduate Centre

KLE Society's S Nijalingappa College

#1040, II Block, Rajajinagar,

Bengaluru-560010

Phone: 080 23526055 / 23325020

## **Proper home address**

Post gudeangadi

Kumta

Uttara Kannada

India.

Phone: 8277049441

e-mail: [ganeshhegde358@gmail.com](mailto:ganeshhegde358@gmail.com)

[ganesh.hegde@learner.manipal.edu](mailto:ganesh.hegde@learner.manipal.edu)

## **Personal information**

Date of Birth : 10-01-1995

Nationality : Indian

Gender : Male

Marital status : Single

Languages known : English, Kannada (Mother tongue), Hindi, Marathi

Present address : Post Rajajinagar, Bangalore 560010

Permanent address : Post Gudeangadi, Kumta, hireoni cross,  
Uttara Kannada, 581351

## **Academic profile**

### **1) Ph. D.**

**Awarded on 15<sup>th</sup> Sept 2022**

Department of Physics

**MIT, MAHE, Manipal**

**Research Supervisor:** Dr. Ashwatha Narayana Prabhu

Assistant professor (Selection grade)

Dept Physics

MIT, MAHE, Manipal

### **2)M.Sc. in Physics (Astrophysics)**

Dept of Physics

Fergusson college affiliated to Savitribai Pule Pune University

Completed in 2018 with CGPA:8.22

### 3) B.Sc. (Physics, Chemistry, Maths)

Dr. A. V. Baliga college of arts and science, Kumta  
Completed in 2016 with 78% (Distinction)

### 4) 10+2 (Physics, Chemistry, Maths, Biology)

Dr. A. V. Baliga PU College of arts and science, Kumta  
Completed in 2013 with 67.5%

### 5) SSLC

CVSK High school, Kumta  
Completed in 2011 with 95.36%

### Research Experience:

My work is focused on **comparative study of thermoelectric properties of single crystals and polycrystalline systems of Low temperature thermoelectric Bismuth metal chalcogenides.**

**Single Crystals:** I have synthesized **high quality single crystal samples of metal bismuth chalcogenides** using the **melt growth technique** and analysed their structural, morphological, and thermoelectric properties in the temperature range 10-350 K.

**Polycrystalline materials:** Polycrystalline samples of **metal bismuth chalcogenides** have been prepared **using solid-state reaction** and studied their structural, morphological, and thermoelectric properties in the temperature range 10-350 K.

**I have worked in Materials Synthesis Lab at UGC-DAE, Mumbai under Dr. P D Babu for PPMS thermoelectric characterizations, Mossbauer Lab at UGC-DAE, Indore under Dr. V R Raghavendra Reddy for HR-XRD Studies and at Materials Research Centre, IISc Bengaluru under Dr. Arun M Umarji for vacuum sealing of thermoelectric materials.**

Till now I have published **11 research articles as first author** and **I have attended and presented my research works in 3 International, 4 National and 1 state level conferences.**

**I have got 130 citations, 8 h Index and 6 i10 index till the year 2023**

### Education Details *(starting from the highest degree)*

Qualification	Year of Passing	Board / University	Percentage/CGPA Scored
Ph.D.	2022(Aug)	Manipal Academy of Higher Education	Defended successfully
M.Sc (Physics)	2018	Fergusson college Pune University	8.2 CGPA
B.Sc (Physics, Chemistry, Maths)	2016	Dr. A. Baliga college of arts and science	78

### Research Publications: *(Scopus, Web of Science, H-Index)*

#### List of Publications in Journals

Sl. No.	Title of the Paper	Authors	Journal Name	Volume	Page No.	Year of Publication	Impact Factor
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1	Enhancement of thermoelectric performance of In doped $\text{Bi}_2\text{Te}_{2.7}\text{Se}_{0.3}$ compounds	<b>Hegde, Ganesh</b> Shridhar, A. N. Prabhu, Ashok Rao, and P. D. Babu	Physica B: Condensed Matter	584	412087	2020	2.436
2	Reduction in thermal conductivity and electrical resistivity of indium and tellurium co-doped bismuth selenide thermoelectric system	<b>Hegde, G. S.,</b> Prabhu, A. N., Huang, R. Y., & Kuo, Y. K.	Journal of Materials and Materials in Electronics	31	19525	2020	2.47
3	Potential thermoelectric materials of indium and tellurium co-doped bismuth selenide single crystals grown by melt growth technique	<b>Hegde, G. S.,</b> Prabhu, A. N., Gao, Y. H., Kuo, Y. K., & Reddy, V. R	Journal of Alloys and Compounds	866	158814	2021	5.316
4	Enhancement in thermoelectric figure of merit of bismuth telluride system	<b>Hegde, Ganesh</b> Shridhar, A. N. Prabhu, Ashok Rao, and M. K. Chattopadhyay.	Materials Science and Semiconductor Processing	127	105645	2021	3.97
5	Improved electrical conductivity and power factor in Sn and Se co-doped melt- grown $\text{Bi}_2\text{Te}_3$ single crystal	<b>Hegde, Ganesh</b> Shridhar, A. N. Prabhu, and M. K. Chattopadhyay.	Journal of Materials Science and Materials in Electronics	20	24871	2021	2.47
6	Reduction in electrical resistivity of bismuth selenide single crystal via Sn and Te co-doping	<b>Hegde, Ganesh</b> Shridhar, A. N. Prabhu, R. Y. Huang, and Y. K. Kuo	Materials Chemistry and Physics	278	125675	2022	4.094
7	A Review on Doped/Composite Bismuth Chalcogenide Compounds for Thermoelectric Device Applications: Various Synthesis Techniques and Challenges	<b>Hegde, Ganesh Shridhar,</b> and A. N. Prabhu.	Journal of Electronic Materials	51	2014	2022	1.98
8	Structural and optical characterization of novel nitro substituted D- $\pi$ -A- $\pi$ -A type chalcone single crystal showing second-order and third-order nonlinear optical properties..	Parol, V., Upadhyaya, V., <b>Hegde, G. S.,</b> Lokanath, N. K., & Prabhu, A. N.	Physica B: Condensed Matter	580	4598	2019	2.9
9	Thermoelectric properties of co-doped $(\text{Bi}_{0.98}\text{In}_{0.02})_2\text{Te}_{2.7}\text{Se}_{0.3}$ /reduced graphene oxide composites prepared by solid-state reaction	<b>Hegde, Ganesh Shridhar,</b> Vinay Parol, Ashok Rao, A. N. Prabhu, Joshua JB Levinsky, and Graeme R. Blake.	Materials research Bulletine	145	111517	2022	4.64

10	Investigation of near room and high temperature thermoelectric properties of (Bi <sub>0.98</sub> In <sub>0.02</sub> ) <sub>2</sub> Se <sub>2.7</sub> Te <sub>0.3</sub> /Bi <sub>2</sub> Se <sub>3</sub> composite system	<b>Ganesh Hegde</b> , Ashok Rao, A. N. Prabhu, Gurukrishna K, Deepika S	Journal of Materials Science and Materials in Electronics	Accepted	Accepted	Accepted	Accepted
11	Thermoelectric composite of (Bi <sub>0.98</sub> In <sub>0.02</sub> ) <sub>2</sub> Te <sub>2.7</sub> Se <sub>0.3</sub> /Bi <sub>2</sub> Se <sub>3</sub> with enhanced thermopower and reduced electrical resistivity ( <i>Post PhD research article</i> )	<b>Ganesh Shridhar Hegde<sup>a</sup></b> , A. N. Prabhu <sup>b*</sup> , Suchitra Putran <sup>b</sup> , Ashok Rao <sup>c</sup> , Gurukrishna K <sup>c</sup> , Deepika Shanubhogue U <sup>c</sup>	Journal of electronic materials	Accepted	Accepted	Accepted	Accepted
12	Influence of indium and selenium co-doping on structural and thermoelectric properties of Bi <sub>2</sub> Te <sub>3</sub> alloys	<b>Ganesh Shridhar Hegde<sup>a</sup></b> , A. N. Prabhu <sup>b*</sup> , M. K. Chattopadhyay <sup>c</sup>	Journal of materials science: Materials in electronics	Accepted	Accepted	Accepted	Accepted
13	Enhancing the thermoelectric power factor by lowering the electrical resistivity of Bi <sub>2</sub> Se <sub>3</sub> /NaI composites prepared by solid-state reaction ( <b>First corresponding paper with Master students</b> )	<b>Ganesh Shridhar Hegde</b> A. N. Prabhu, Ashok Rao, Deepika Shanubhogue U, Suchitra Putran	Journal of electronic materials	Accepted	Accepted	Accepted	Accepted
14	Thermoelectric analysis of (Bi <sub>0.98</sub> In <sub>0.02</sub> ) <sub>2</sub> Te <sub>2.7</sub> Se <sub>0.3</sub> / Polyaniline and (Bi <sub>0.98</sub> In <sub>0.02</sub> ) <sub>2</sub> Se <sub>2.7</sub> Te <sub>0.3</sub> /Polyaniline composites	<b>Ganesh Shridhar Hegde</b> A. N. Prabhu,	materials science: Materials in electronics	Accepted	Accepted	Accepted	Accepted

### Conferences/Seminars/Workshops/Faculty development programme

Sl. No.	Name of the Event	National/ International	Date	Name of the Organizer	Credits Earned
1	One week international webinar on materials characterization and analysis	International	25-31, 2020	Dept of Physics, Indore	Participation
2	Online workshop on Rietveld refinement	International	22-24,2020	UGC DAE INDORE, MUMBAI	Participation
3	9 <sup>th</sup> national conference on condensed matter physics	National	16-17, Sept, 2021	MAHE, Manipal	Poster presentation
4	8 <sup>th</sup> national conference on condensed matter physics	National	26, Sept, 2020	MAHE, Manipal	Poster presentation
5	8 <sup>th</sup> national conference on condensed matter physics	National	16, 17 Sept 2020	MAHE, Manipal	Poster presentation
6	7 <sup>th</sup> national conference on condensed matter physics	National	16, 17 Sept 2020	MAHE, Manipal	Oral presentation
7	Thermoelectric materials and application for energy harvesting and power generation	International	14 <sup>th</sup> Dec 2021	School of Mechanical Engineering Katra	Participation
8	Physics in Every day life	International	9-11, 2021	Medi caps Indore	Participation

9	International Conference on advanced materials	International	1,2 July	Calicut University	Oral presentation
10	International conference on Advanced materials science and application	International	3-4 Sept 2020	M. S. Rammaya institute of technology	Best oral presentation award
11	State level kannada vijnana sammelana	State	16-17 Sept 2021	Mangalore University	Best research article
12	International winter school on frontiers in materials	international	6-10 Dec 2021	JNCASR	Poster presentation
13	Faculty development programme	National	20 <sup>th</sup> June - 24 <sup>th</sup> June	Christ academy, Bangalore	participant
14	Innovative experiment for physics teachers	Regional	10-July 2022	Maharani laksmi ammani college Bangalore	First prize
15	Resource person in Faculty development Programme	National	Oct 11 <sup>th</sup> 2022	BMS Institute of science and management	
16	International conference on recent trends in materials science 2023	International	March 7 <sup>th</sup> 2023	Kristu Jayanti College Bangalore	Third prize

#### Patents Filed/Approved

1	<i>Improvement of the thermoelectric figure of merit and electrical conductivity in bismuth telluride with tin and tellurium doped system</i>	Indian	Patent No: 202341066866	Manipal Academy of Higher Education	Filed
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**Apart from these, I have a grant of UGC DAE CSR CRS/2022-23/1251 (Project for 3 years) from central govt of rupees 1.5 lac.**

**Editorship has been given to me for the book series under IIP Volume 3 2023**

**I had been an NCC Cadet, cleared C Certificate exam which has taught me discipline, teamwork, critical thinking, and tackle challenges logically. These qualities have helped me in carrying out my research work in an organized manner. I have a teaching experience for 1 year UG and PG course of M.Sc. and B.Sc.**

**By all these, I believe I am an ideal candidate for the present position.**

#### Reference

**(Prof) Dr. Vasudeva Siruguri**

Former Centre Director,

UGC-DAE Consortium for Scientific Research Mumbai Centre

Mumbai, Maharashtra

Contact No: 9969303262

Email id: [siruguri@csr.res.in](mailto:siruguri@csr.res.in)

**(Prof) Dr. Ashok Rao**

Associate Director

Research and Consultancy

Manipal Institute of Technology

MAHE, Manipal

Contact No.: 9916067593

Email Id: [a.rao@manipal.edu](mailto:a.rao@manipal.edu)

**Dr. RAJEEV SHESHA JOSHI**

Assistant Professor  
School of Physical Sciences,  
Central University of Karnataka,  
Aland Road, Kadaganchi,  
Gulbarga, Karnataka-585311  
Email Id: rajeevsj@cuk.ac.in

**Dr. Ashwatha Narayana Prabhu**

Assistant Professor (Selection grade)  
Crystal growth lab in charge  
Department of Physics  
Manipal Institute of Technology  
MAHE  
Contact No.: 9964586628  
Email id: [ashwatha.prabhu@manipal.edu](mailto:ashwatha.prabhu@manipal.edu)

**Declaration:**

**I hereby declare that the details stated above are true and correct to the best of my knowledge.**